

Lecture 6: Optical properties of organic semiconductors

Ref.

- M. Pope and C. E. Swenberg. *Electronic Processes in Organic Crystals and Polymers*, 2nd Ed. (Oxford, NY, 1999)

2009. 3. 26 & 31

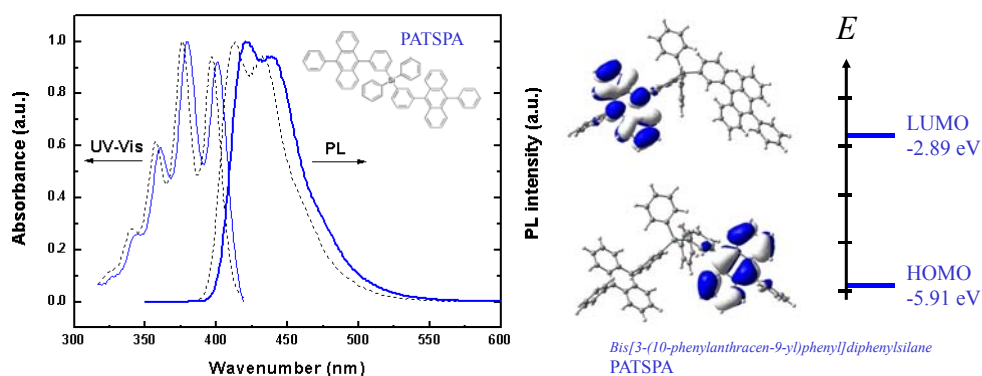
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Absorption and PL of PATSPA



Y.-Y. Lyu, J. H. Kwak, O. H. Kwon, S.-H. Lee, D. Y. Kim, C. H. Lee, and K. H. Char, *Adv. Mater.* **20** (2008).

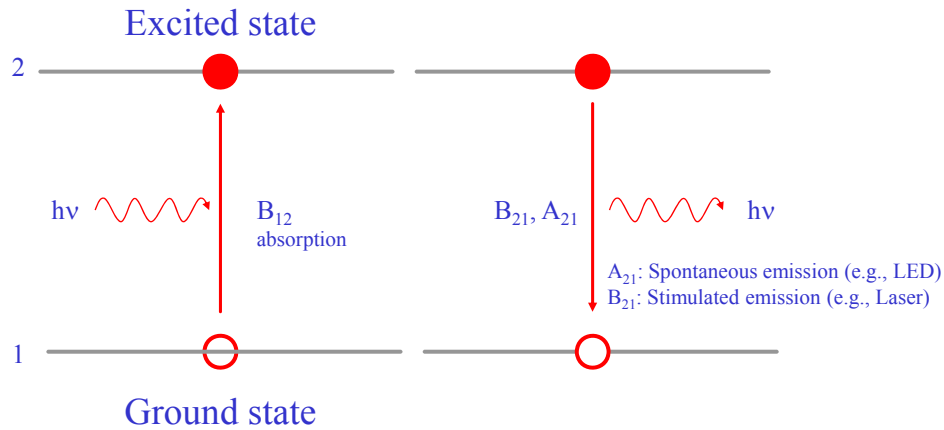


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Absorption and Emission of Light

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Selection Rules for Electronic Transition

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Fermi Golden Rule

Electric dipole transition rate from i to f state:

$$\Gamma_{i \rightarrow f} = \frac{4\pi^2}{\hbar^2 c} |\vec{\epsilon} \cdot \langle \psi_f | \vec{d} | \psi_i \rangle|^2 I(\omega_{fi})$$

Oscillator strength for the transition $f \propto |\vec{\epsilon} \cdot \langle \psi_f | \vec{d} | \psi_i \rangle|^2$

Dipole moment operator $\vec{d} = -e \sum_j \vec{r}_j$

• For the allowed transition $\Delta l = \pm 1, \Delta S = 0$

• **Symmetry selection rule:** only g (even parity) \leftrightarrow u (odd parity) transitions are allowed.

(The vibrational motions may lower the symmetry of a molecule, so that symmetry-forbidden transitions may be observed)

• **Spin selection rule:** no change in spin multiplicity

$$H_{so} = \frac{Ze^2}{2m^2 c^2} \frac{1}{r^3} \vec{L} \cdot \vec{S} \propto Z^4$$

(The spin-orbit coupling allows the mixing of singlet and triplet states)

Eg., Transition from 2p to 1s state in a H atom

$$\Gamma_{2p \rightarrow 1s} \approx 0.6 \times 10^9 \text{ s}^{-1} \quad \tau = \frac{1}{\Gamma_{2p \rightarrow 1s}} \approx 1.6 \text{ ns}$$



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Consider a molecule with two energy levels 1 and 2.

The rate of transition B_{12} induced by light of frequency ν

$$\Gamma_{1 \rightarrow 2} = B_{12} I(\omega_{fi})$$

$$B_{12} = \frac{2\pi}{3\hbar^2} \left| \langle \psi_2 | \vec{d} | \psi_1 \rangle \right|^2$$

Transition rate for $1 \rightarrow 2$ (absorption): $B_{12} I(\nu) N_1$

Transition rate for $2 \rightarrow 1$ (emission): $[B_{21} I(\nu) + A_{21}] N_2$

N_1 (N_2) = population of the level 1 (level 2).

A_{21} = spontaneous emission from the level 1 to the level 2.

At equilibrium the rate of transition $1 \leftrightarrow 2$ must be the same.

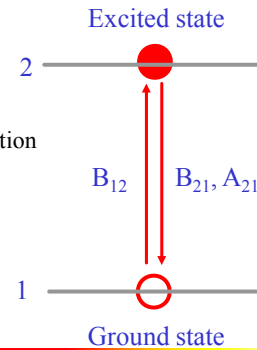
$$\frac{N_1}{N_2} = \frac{B_{21} I(\nu) + A_{21}}{B_{12} I(\nu)} = 1 + \frac{A_{21}}{B_{12} I(\nu)} \quad (1)$$

But at equilibrium, N_1 and N_2 in each level is given by the Boltzmann equation

$$\frac{N_1}{N_2} = \exp\left(\frac{E_2 - E_1}{kT}\right) = \exp\left(\frac{h\nu}{kT}\right) \quad (2)$$

Equation 1 and 2 must be equal. Therefore, we can obtain $I(\nu)$.

$$I(\nu) = \frac{A_{21} / B_{21}}{(B_{12} N_1 / B_{21} N_2) - 1} = \frac{A_{21} / B_{21}}{\frac{B_{12}}{B_{21}} e^{\frac{h\nu}{kT}} - 1} \quad (3)$$



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At equilibrium $I(\nu)$ is the radiation density of a black body at temperature T : Planck's radiation law.

$$I(\nu) = \frac{8\pi h \nu^3}{c^3} \frac{1}{e^{\frac{h\nu}{kT}} - 1} \quad (4)$$

By comparing the like terms in equations (3) and (4), the Einstein coefficients can be obtained to give

$$B_{12} = B_{21} \quad (5)$$

The stimulated emission process occurs at the same rate as the absorption process. And we can get

$$\frac{A_{21}}{B_{21}} = \frac{8\pi h \nu^3}{c^3} = \frac{8\pi h}{\lambda^3} \quad (6)$$

The rate of spontaneous to stimulated emission increases as ν^3 . B_{12} can be measured from the absorption spectrum.

The radiative lifetime:

$$\tau_r = \frac{1}{A_{21}} = \frac{c^3}{8\pi h \nu^3 B_{12}} = \frac{\lambda^3}{8\pi h B_{12}}$$

The stronger the absorption, the shorter the radiative lifetime. And the radiative lifetime decreases with increasing frequency (or decreasing wavelength).



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Absorption of Light

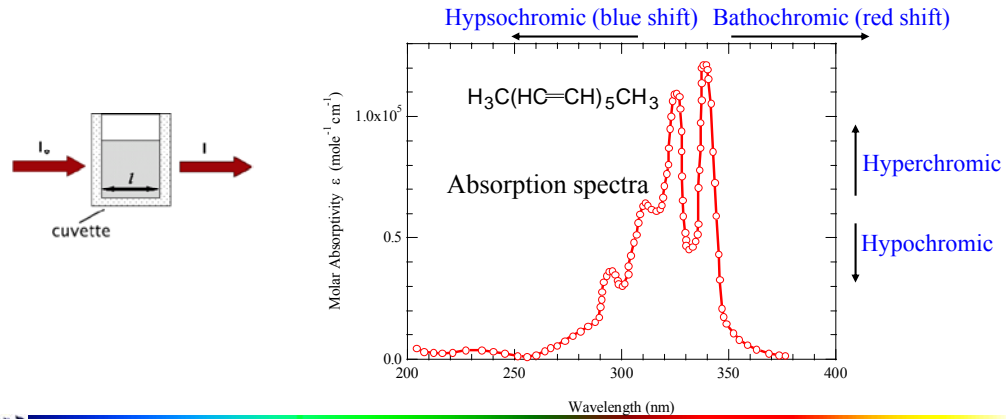
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The Beer-Lambert Law:

$$\text{Absorbance} = \log\left(\frac{I_0}{I}\right) = \epsilon cl$$

I_0 and I are the intensities entering and leaving the sample, respectively. ϵ = the molar extinction coefficient or molar absorptivity, c = sample concentration in moles/liter, l = length of light path through the sample in cm.

Molar Absorptivity, $\epsilon = A / c l$, where A = absorbance (Optical Density)

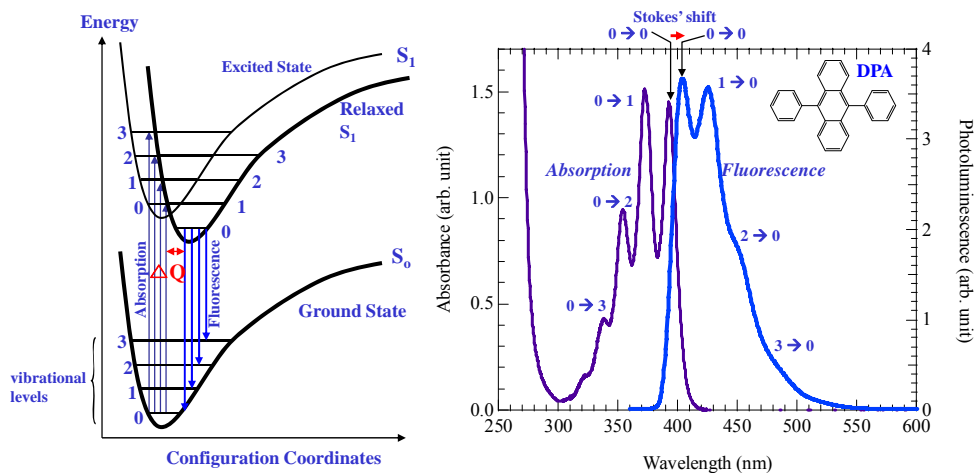


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Absorption and PL of DPA

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<http://omlc.ogi.edu/spectra/PhotochemCAD/html/diphenyl-anthracene.html>
9,10-Diphenylanthracene dissolved in cyclohexane.



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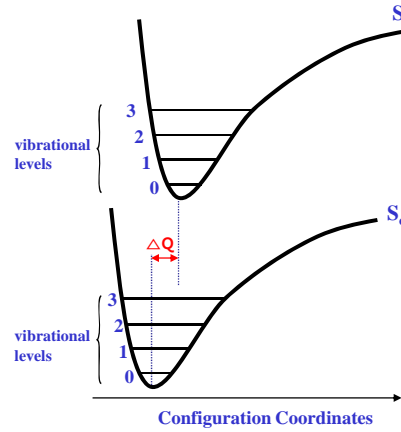
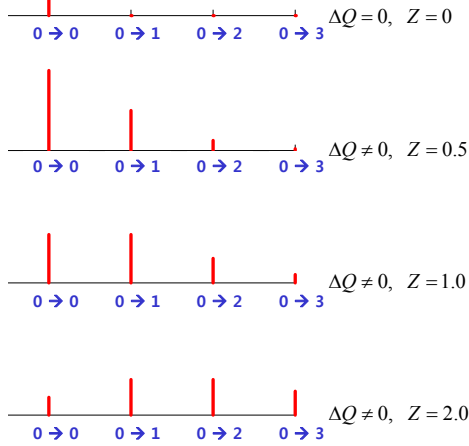
Franck-Condon intensity distribution

Vibronic intensity distribution :

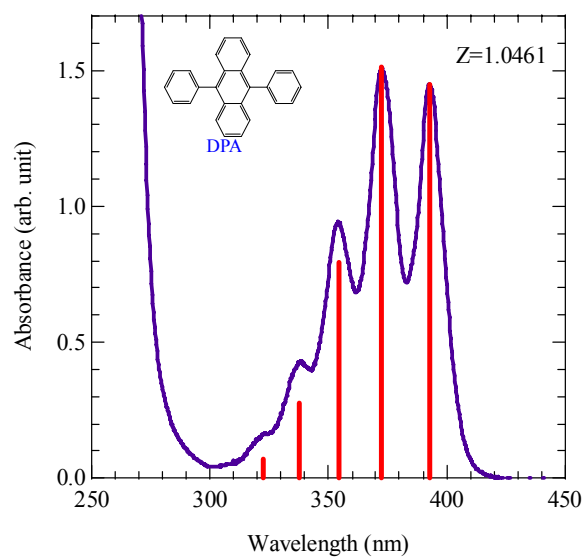
$$I(n) = \frac{Z^n}{n!} e^{-Z} : \text{Poisson distribution}$$

Huang - Rhys parameter :

$$Z = \frac{1}{2\hbar\omega} k(\Delta Q)^2 = \frac{M\omega}{2\hbar} (\Delta Q)^2 = \frac{E_d}{\hbar\omega} = n + \frac{1}{2}$$

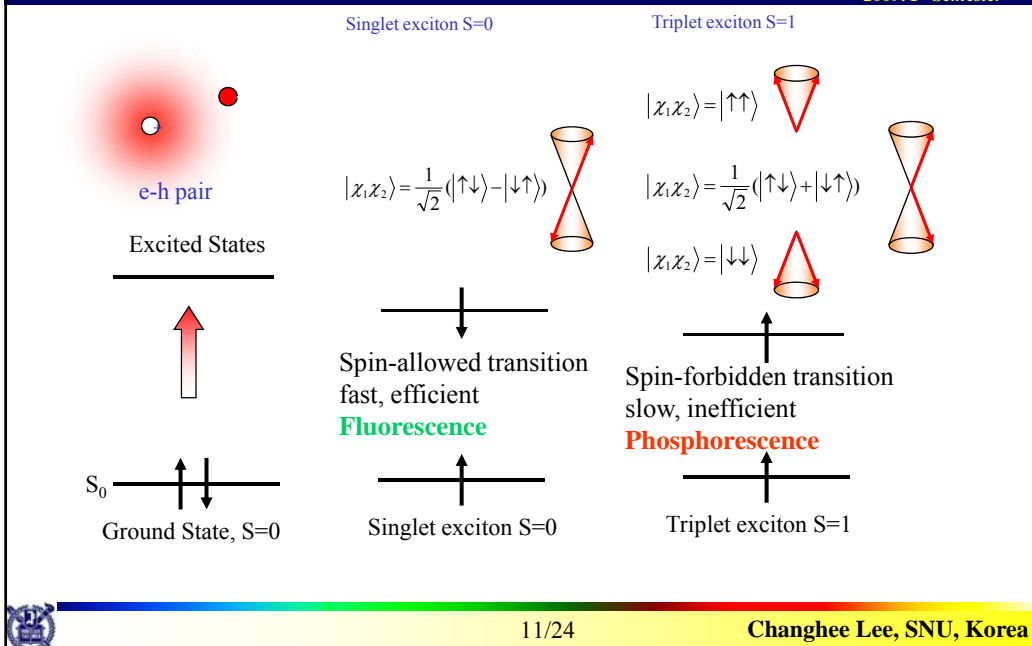


Franck-Condon intensity distribution: an example



Singlet & Triplet Excitons

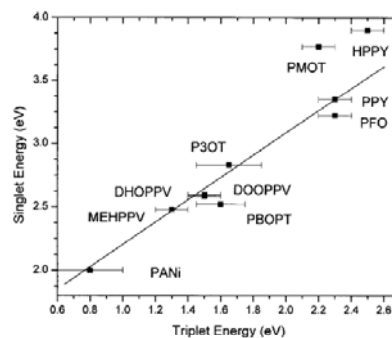
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Energy difference between Singlet-Triplet exciton energy

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- Triplet state is at lower energy than the singlet state:
- Electrons in singlet state have the antisymmetric spins, thus can have the same position in space, resulting in a large electron-electron repulsion energy.
- Electrons in triplet state have the symmetric spins, thus cannot have the same position in space, reducing the electron-electron repulsion energy.
- The S - T splitting is inversely proportional to orbital size, because the electrons will on average be further apart
- The S - T splitting is proportional to orbital overlap, thus electrons promoted from substituent atomic orbitals to conjugated π -orbitals will have a small splitting.

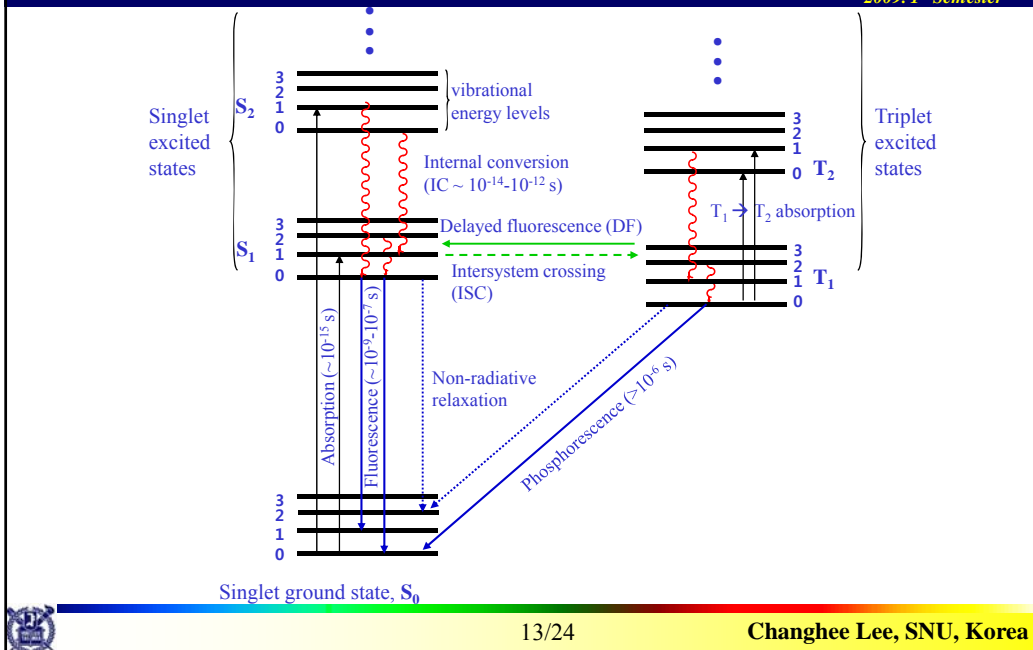


A. Monkman et al., Phys. Rev. Lett. **6**, 1358 (2001)

anthracene:	$S_1 - T_1 = 1.5$ eV
tetracene	1.3 eV
pentacene	1.1 eV

Jablonski Energy Diagram

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Energy Transfer Processes

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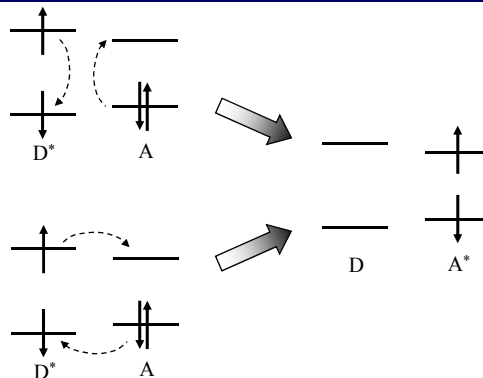
Förster Transfer Process
Dipole-dipole interaction
(overlap of PL and Abs spectra)
long range ~ 30 - 100 Å

$$k_{D \rightarrow A} = \frac{K^2 J 8.8 \times 10^{-28} \text{ mol}}{n^4 \tau_D r^6}$$

Dexter Transfer Process
Electron exchange
(overlap of wavefunctions)
short range ~ 5 - 20 Å

$$k_{ET} \propto \frac{h}{2\pi} P^2 J \exp(-2r/L)$$

$$\text{Overlap integral : } J = \int \frac{\epsilon_A(\tilde{\nu}) \cdot F_D(\tilde{\nu})}{\tilde{\nu}^4} d\tilde{\nu}$$



The Förster eq. is often written in the following form:

$$W_{DA} = k_r^D \left(\frac{R_0}{R} \right)^6 \quad R_0^6 = 8.8 \cdot 10^{17} \cdot \frac{\kappa^2}{n^4} \cdot \int \frac{\epsilon_A(\tilde{\nu}) \cdot F_D(\tilde{\nu})}{\tilde{\nu}^4} d\tilde{\nu}$$

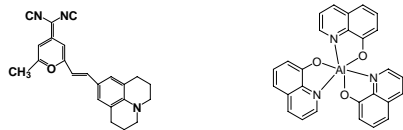
For photosynthetic systems R is typically 1 nm, R_0 is typically 8 nm, $k_r^D \approx 5 \cdot 10^7 \text{ s}^{-1} \rightarrow W_{DA} \approx 10^{13} \text{ s}^{-1}$

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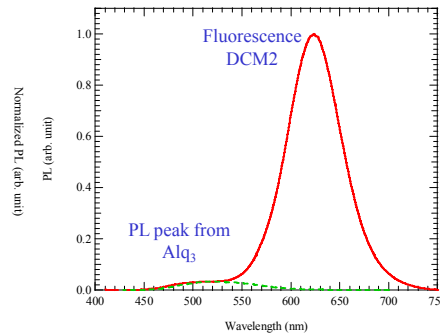
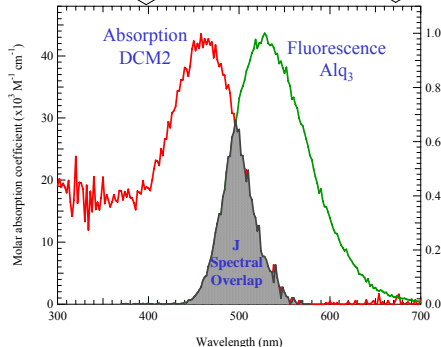
Calculation of Forster exciton energy transfer

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$$J = \frac{\int_0^\infty \lambda^4 F_d(\lambda) \epsilon_a(\lambda) d\lambda}{\int_0^\infty F_d(\lambda) d\lambda}$$

$$R_0^6 = 8.79 \times 10^{-3} \left(\frac{\kappa^2 Q_d}{n^4} J \right) \text{Å}^6; R_0 = 0.21 \left(\frac{\kappa^2 Q_d}{n^4} J \right)^{1/6} \text{Å}$$



Wavelength (nm)
Molar extinction coefficient of DCM: $\epsilon_c(\lambda) \sim 4 \times 10^4 \text{ M}^{-1} \text{ cm}^{-1}$ [J. Appl. Phys. 84 (8), 4096 (1998)]
Dipole orientation factor, $\kappa^2=2/3$ for random orientation
Refractive index medium $n=1.7$
Fluorescent quantum efficiency of donor: QE~35% Alq₃, [J. Appl. Phys. 84 (8), 4096 (1998)]
→ Forster radius $R_0=3.37 \text{ nm}$

Ref. "Topics in Fluorescence Spectroscopy, vol. 2, Principles, ed. By Joseph R. Lakowicz (Plenum, New York, 1991), pp.129-130.

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Experimental results of Forster energy transfer in optically pumped organic semiconductor thin films

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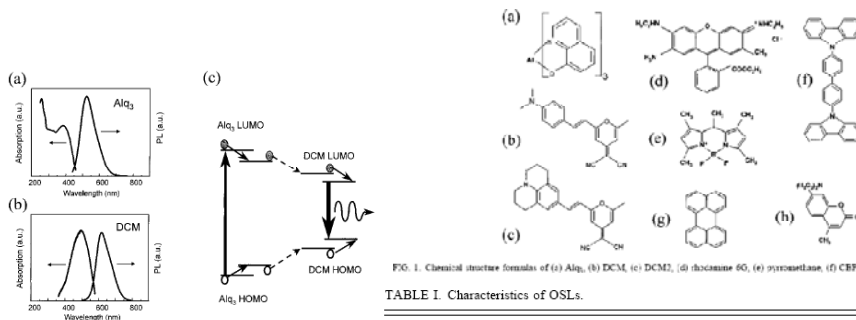


FIG. 1. Chemical structure formulas of (a) Alq₃, (b) DCM, (c) DCM2, (d) rhodamine 6G, (e) pyromethane, (f) CBP, (g) perylene, (h) coumarin 47.

TABLE I. Characteristics of OSLs.

Laser material	Forster radius (Å)	Lasing wavelength (nm)	Lasing threshold ^a ($\mu\text{J}/\text{cm}^2$)	Operating lifetime at $P=500 \mu\text{J}/\text{cm}^2$ (No. of pump laser pulses)	Differential quantum efficiency ^b (%)
Alq ₃ -DCM	32	615–660	3	$>10^6$	30%
Alq ₃ -DCM2	39	655–700	2.5	$>10^5$	30%
Alq ₃ -rhodamine 6G	41	610–625	35	10^3	– ^c
Alq ₃ -pyromethane 546	38	560	15	$>10^5$	5%
CBP:perylene	28	485	5	$>10^5$	15%
CBP:coumarin 47	30	460	15	10^3	– ^c

^aLasing thresholds are for 5 mm long slab waveguide OSLs.

^bDifferential quantum efficiencies are for 1 mm long slab waveguide OSLs.

^cNot measured due to rapid degradation.

V. G. Kozlov, V. Bulovic, P. E. Burrows, M. Baldo, V. B. Khalfin, G. Parthasarathy, S. R. Forrest, Y. You and M. E. Thompson, J. Appl. Phys. 84 (8), 4096 (1998)

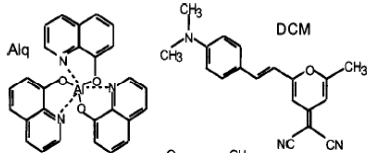
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Experimental result of Förster radius

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Excitation dynamics of dye doped tris(8-hydroxy quinoline) aluminum films



$$R_0^6 = \frac{0.529 \kappa^2}{n^4 N_A} \int \frac{\epsilon_A(\tilde{\nu}) \cdot F_D(\tilde{\nu})}{\tilde{\nu}^4} d\tilde{\nu}$$

κ =donor/acceptor orientation factor;
 $\kappa^2 = 2/3$ for a randomly deposited film
 N_A is Avogadro's number
 $n=1.7$ for Alq3

$$R_0 = 31 \text{ \AA}$$

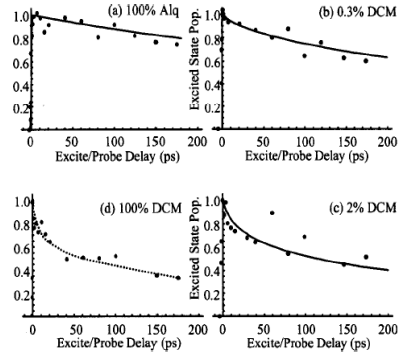


FIG. 3. Excited state population as a function of excite/probe delay for the sample compositions (a) 100% Alq, (b) Alq+0.3%DCM, (c) Alq +2%DCM, and (d) 100% DCM. The 100% DCM sample was excited with $68 \mu\text{J}/\text{cm}^2$, and all others were excited with $91 \mu\text{J}/\text{cm}^2$ (1.8×10^{27} photons/cm²) of 90 fs 3.14 eV laser pulses. The solid curve, (a) represents bimolecular singlet annihilation. The solid curves, (b) and (c), are from fits including excitation transfer, excimer formation, and stimulated emission. The dotted curve, (d), is only a guide to the eye.

K. Read, H. S. Karlsson, M. M. Murnane and H. C. Kapteyn, R. Haight, J. Appl. Phys. **90**, 294 (2001)



Experimental result of Förster radius

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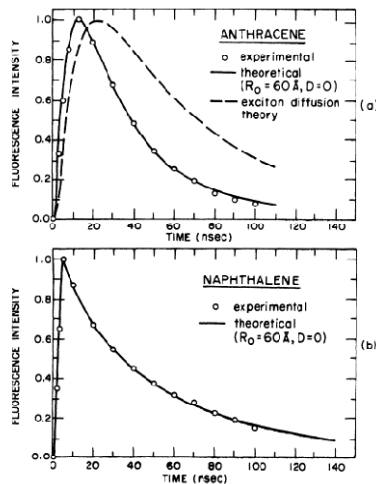


FIG. 1. Time dependence of the fluorescence intensities of naphthalene doped with $4.7 \times 10^{17} \text{ cm}^{-3}$ anthracene after pulsed x-ray excitation (see text for explanation of the theoretical lines).

R. C. Powell, Phys. Rev. B **4**, 628 (1971)

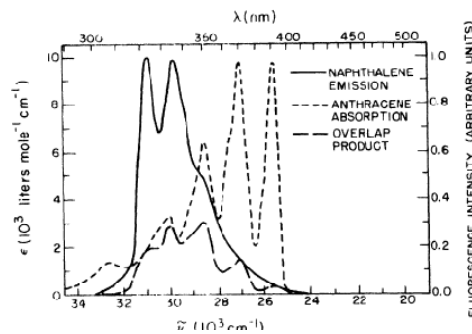


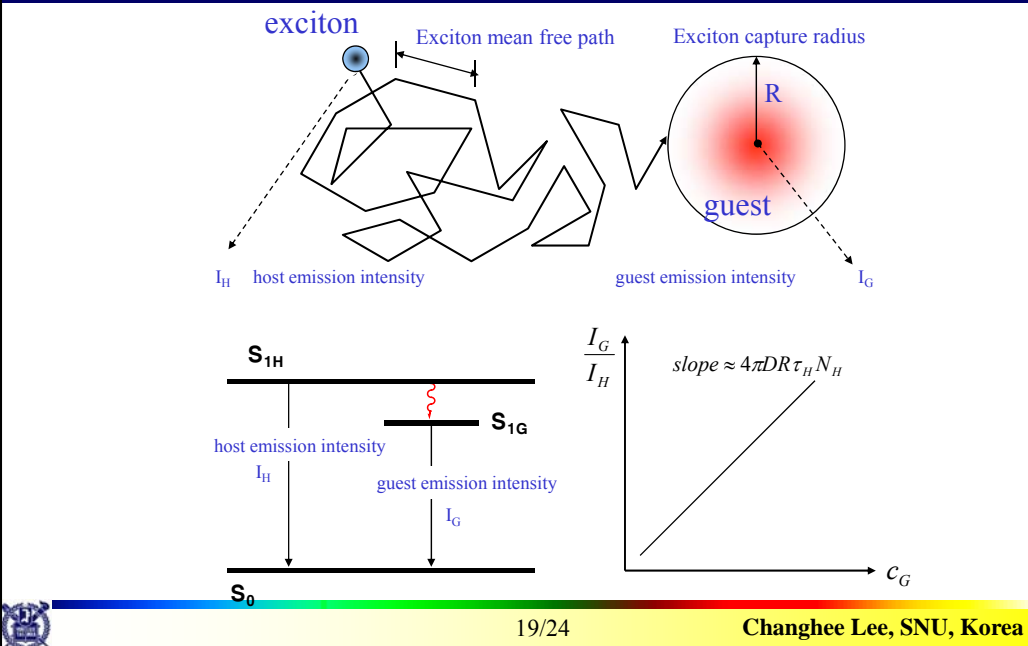
TABLE I. Summary of measured decay times and theoretical and experimental values for t_n and R_0 .

Parameter	System			
	Undoped naphthalene	Naphthalene: anthracene	Naphthalene: tetracene	Naphthalene: anthracene and tetracene
Fluorescence decay time of naphthalene	85 nsec			
Fluorescence decay time of anthracene and tetracene in naphthalene		10 nsec	13 nsec	
Measured t_n for lightly doped samples		12 nsec	18 nsec	8 nsec
Predicted t_n from exciton diffusion		23 nsec	28 nsec	
R_0 needed to fit data		60 Å	60 Å	28 Å
Theoretically predicted R_0		23 Å	12 Å	28 Å



Exciton diffusion

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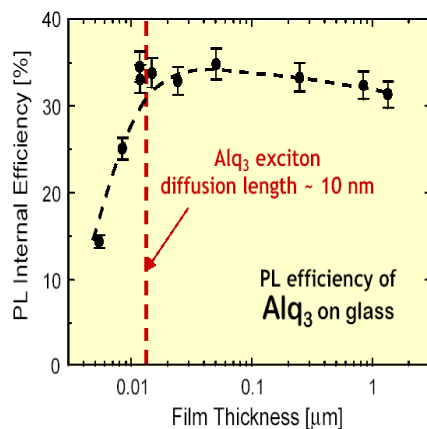
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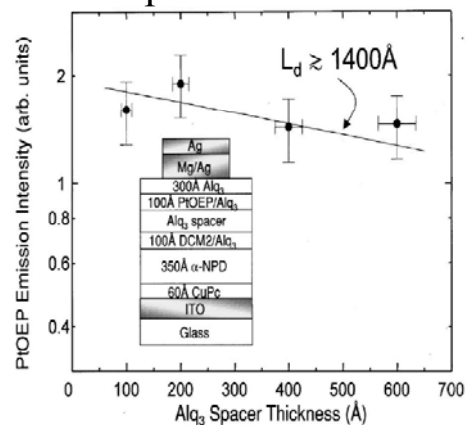
Diffusion Length of Excitons

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Singlet Exciton



Triplet Exciton



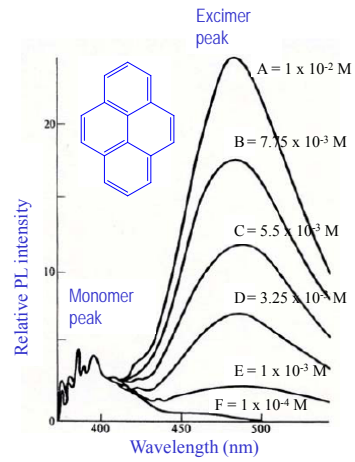
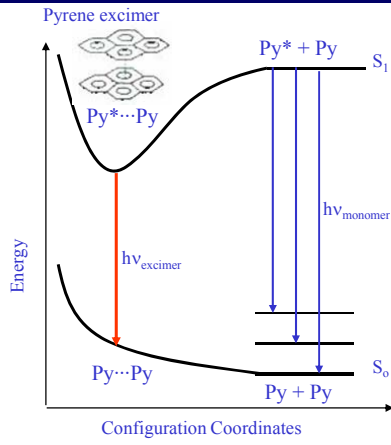
Long L_d for triplet exciton requires an exciton blocking layer

M.A. Baldo, D.F. O'Brien, Y. You, A. Shoustikov, S. Sibley, M.E. Thompson, S.R. Forrest, Nature 395 (1998) 151.
D.F. O'Brien, M.A. Baldo, M.E. Thompson, S.R. Forrest, Appl. Phys. Lett. 74 (1999) 442.

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Excimer or Exciplex



Excited state dimer; Repulsive ground state

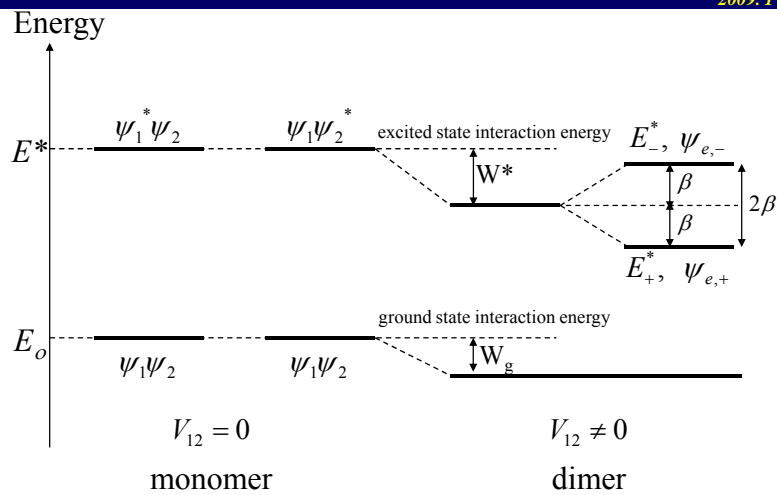
Excimer: M+M*

Exciplex: D+A* or D*+A

- Red shift
- Broad peak with no vibronic structure

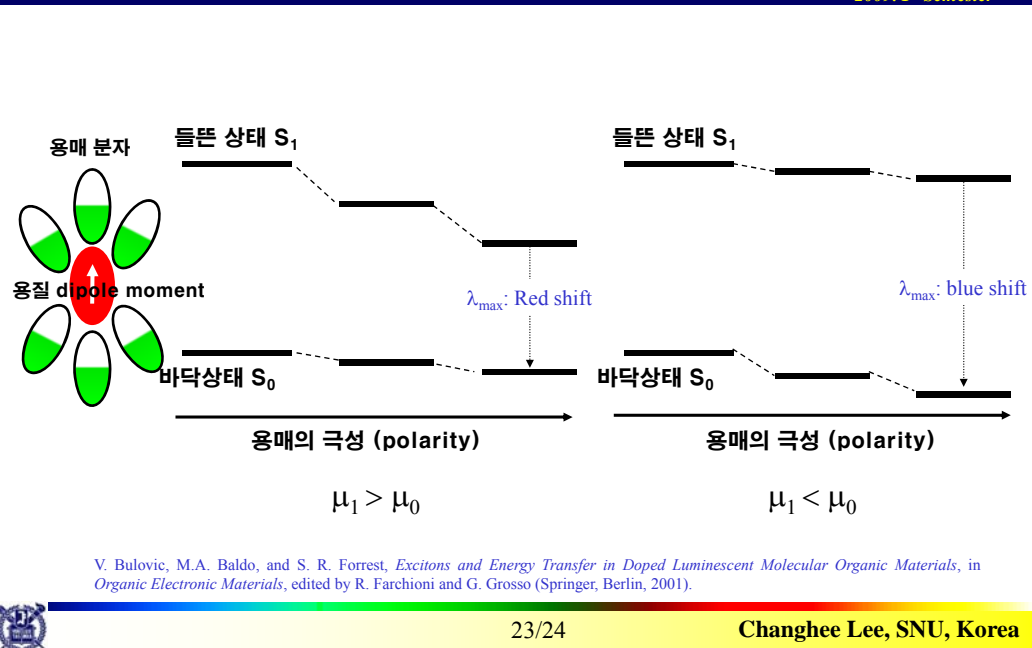


Davidov splitting



Host - Dopant Interaction

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Self-aggregation of molecules

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The self-association of dyes in solution or at the solid-liquid interface is a frequently encountered phenomenon owing to strong intermolecular van der Waals-like attractive forces between the molecules.

J-aggregate (J for Jelly, one of the first workers who investigated these shifts). Bathochromically shifted (red-shift): E. E. Jelly, *Nature* 1936, 138, 1009.

H-aggregate (H for hypsochromic): Hypsochromically shifted (blue-shifted). L. G. S. Brooker, F. L. White, D. W. Heseltine, G. H. Keyes, S. G. Dent, E. J. VanLare, *J. Photogr. Sci.* 1953, 1, 173.

